

October 1987 Revised January 1999

CD4724BC 8-Bit Addressable Latch

General Description

The CD4724BC is an 8-bit addressable latch with three address inputs (A0–A2), an active low enable input (\overline{E}) , active high clear input (CL), a data input (D) and eight outputs (Q0–Q7).

Data is entered into a particular bit in the latch when that is addressed by the address inputs and the enable (\overline{E}) is LOW. Data entry is inhibited when enable (\overline{E}) is HIGH.

When clear (CL) and enable (\overline{E}) are HIGH, all outputs are LOW. When clear (CL) is HIGH and enable (\overline{E}) is LOW, the channel demultiplexing occurs. The bit that is addressed has an active output which follows the data input while all unaddressed bits are held LOW. When operating in the addressable latch mode $(\overline{E}=CL=LOW)$, changing more than one bit of the address could impose a transient wrong

address. Therefore, this should only be done while in the memory mode ($\overline{E}=HIGH,\,CL=LOW).$

Features

- Wide supply voltage range: 3.0V to 15V
- High noise immunity: 0.45 V_{DD} (typ.)
- Low power TTL compatibility: fan out of 2 driving 74L or 1 driving 74LS
- Serial to parallel capability
- Storage register capability
- Random (addressable) data entry
- Active high demultiplexing capability
- Common active high clear

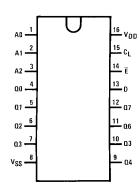
Ordering Code:

Order Number	Package Number	Package Description
CD4724BCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
CD4724BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignments for DIP and SOIC



Top View

Truth Table

	Mode Selection								
E	CL	Addressed	Unaddressed	Mode					
		Latch	Latch						
L	L	Follows Data	Holds Previous Data	Addressable Latch					
Н	L	Hold Previous Data	Holds Previous Data	Memory					
L	Н	Follows Data	Reset to "0"	Demultiplexer					
Н	Н	Reset to "0"	Reset to "0"	Clear					

Absolute Maximum Ratings(Note 1)

(Note 2)

Power Dissipation (P_D)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T_L)

(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3.0V to 15 V_{DC} Input Voltage (V_{IN}) 0V to V_{DD} V_{DC}

Operating Temperature Range (T_A) -40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and Electrical Characteristics" provide conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	-40	–40°C		+25°C			+85°C	
Syllibol	raiailletei	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device	$V_{DD} = 5V$		20		0.02	20		150	μΑ
	Current	$V_{DD} = 10V$		40		0.02	40		300	μΑ
		$V_{DD} = 15V$		80		0.02	80		600	μΑ
V _{OL}	LOW Level	I _O ≤ 1 μA								
	Output Voltage	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
V _{OH}	HIGH Level	I _O ≤ 1 μA								
OII	Output Voltage	$V_{DD} = 5V$	4.95		4.95	5.0		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		V
V _{IL}	LOW Level	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$		1.5		2.25	1.5		1.5	V
	Input Voltage	$V_{DD} = 10V, V_{O} = 1V \text{ or } 9V$		3.0		4.5	3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$		4.0		6.75	4.0		4.0	V
V _{IH}	HIGH Level	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$	3.5		3.5	2.75		3.5		V
	Input Voltage	$V_{DD} = 10V, V_{O} = 1V \text{ or } 9V$	7.0		7.0	5.5		7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$	11.0		11.0	8.25		11.0		V
I _{OL}	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.52		0.44	0.88		0.36		mA
	Current	$V_{DD} = 10V, V_{O} = 0.5V$	1.3		1.1	2.25		0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 1.5V$	3.6		3.0	8.8		2.4		mA
I _{OH}	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.52		-0.44	-0.88		-0.36		mA
	Current	$V_{DD} = 10V, V_{O} = 9.5V$	-1.3		-1.1	-2.25		-0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 13.5V$	-3.6		-3.0	-8.8		-2.4		mA
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.30		-10 ⁻⁵	-0.30		-1.0	μА
		$V_{DD} = 15V, V_{IN} = 15V$		0.30		10 ⁻⁵	0.30		1.0	μА

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Note 3: I_{OL} and I_{OH} are tested one output at a time.

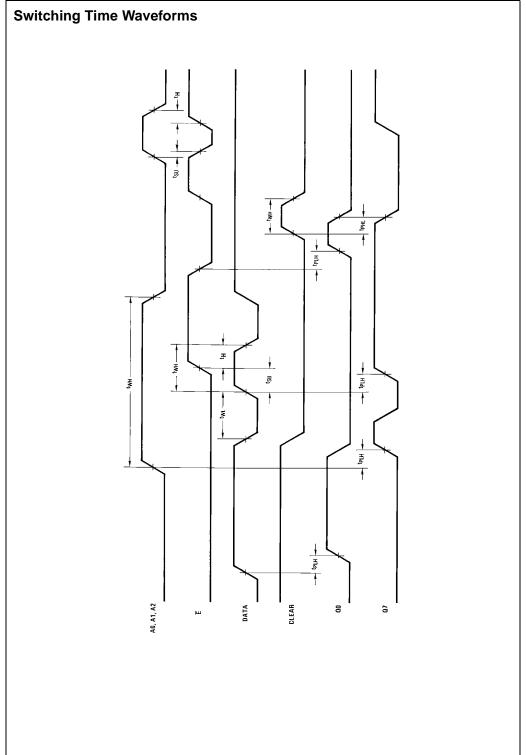
AC Electrical Characteristics (Note 4)

 $T_A = 25$ °C, $C_L = 50$ pF, $R_L = 200$ k, Input $t_f = t_f = 20$ ns, unless otherwise noted

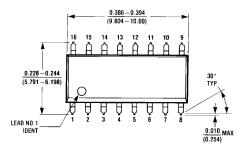
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHL} tPLH	Propagation Delay	V _{DD} = 5V		200	400	ns
	Data to Output	V _{DD} = 10V		75	150	ns
		V _{DD} = 15V		50	100	ns
t _{PLH} , t _{PHL}	Propagation Delay	V _{DD} = 5V		200	400	ns
	Enable to Output	V _{DD} = 10V		80	160	ns
		V _{DD} = 15V		60	120	ns
t _{PHL}	Propagation Delay	$V_{DD} = 5V$		175	350	ns
	Clear to Output	V _{DD} = 10V		80	160	ns
		V _{DD} = 15V		65	130	ns
t _{PLH} , t _{PHL}	Propagation Delay	$V_{DD} = 5V$		225	450	ns
	Address to Output	$V_{DD} = 10V$		100	200	ns
		$V_{DD} = 15V$		75	150	ns
t _{THL} , t _{TLH}	Transition Time	$V_{DD} = 5V$		100	200	ns
	(Any Output)	$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	ns
T _{WH} , T _{WL}	Minimum Data	$V_{DD} = 5V$		100	200	ns
	Pulse Width	$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	ns
t _{WH} , t _{WL}	Minimum Address	V _{DD} = 5V		200	400	ns
	Pulse Width	$V_{DD} = 10V$		100	200	ns
		$V_{DD} = 15V$		65	125	ns
t _{WH}	Minimum Clear	$V_{DD} = 5V$		75	150	ns
	Pulse Width	$V_{DD} = 10V$		40	75	ns
		$V_{DD} = 15V$		25	50	ns
t _{SU}	Minimum Setup Time	$V_{DD} = 5V$			ns	
	Data to E	$V_{DD} = 10V$		20	40	ns
		$V_{DD} = 15V$		15	50 80 40 30	ns
t _H	Minimum Hold Time	$V_{DD} = 5V$		60	160 130 450 200 150 200 100 80 200 100 80 400 200 125 150 75 50 80 40	ns
	Data to E	$V_{DD} = 10V$		30	60	ns
		$V_{DD} = 15V$		25	50	ns
t _{SU}	Minimum Setup Time	$V_{DD} = 5V$		-15	50	ns
	Address to E	$V_{DD} = 10V$		0	30	ns
		$V_{DD} = 15V$		0	20	ns
t _H	Minimum Hold Time	$V_{DD} = 5V$		-50	15	ns
	Address to E	V _{DD} = 10V		-20	10	ns
		V _{DD} = 15V		-15	5	ns
C _{PD}	Power Dissipation	Per Package		100		pF
	Capacitance	(Note 5)				
C _{IN}	Input Capacitance	Any Input		5.0	7.5	pF

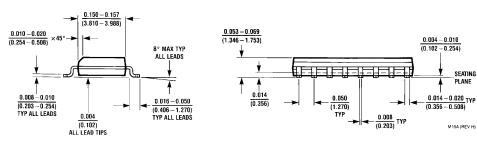
Note 4: AC Parameters are guaranteed by DC correlated testing.

Note 5: Dynamic power dissipation (P_D) is given by: $P_D = (C_{PD} + C_L) \ V_{CC}^2 f + P_Q$; where $C_L = \text{load capacitance}$; f = frequency of operation; for further details, see Application Note AN-90, "Family Characteristics".

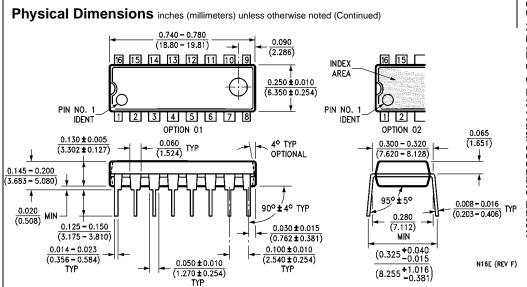


Physical Dimensions inches (millimeters) unless otherwise noted





16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body Package Number M16A



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N16E

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